An Ultra-small $40 \mathrm{~m} \Omega, 1 \mathrm{~A}$,
Load Switch with Discharge

## General Description

The SLG59M1440V is designed for load switching applications. The part comes with one $40 \mathrm{~m} \Omega, 1$ A rated MOSFET controlled by a single ON control pin. The MOSFET's ramp rate is adjustable depending on the input current level of the ON pin.
The product is packaged in an ultra-small $1.0 \times 1.0 \mathrm{~mm}$ package.

## Features

- One $40 \mathrm{~m} \Omega, 1$ A MOSFET
- One integrated VGS Charge Pump
- User selectable ramp rate with external resistor
- Integrated Discharge Resistor
- Over Temperature Protection
- Pb-Free / Halogen-Free / RoHS compliant
- STDFN 4L, $1.0 \times 1.0 \times 0.55 \mathrm{~mm}$

Pin Configuration


4-pin STDFN
(Top View)

Block Diagram


An Ultra-small $40 \mathrm{~m} \Omega, 1 \mathrm{~A}$, Load Switch with Discharge

## Pin Description

| Pin \# | Pin Name | Type | Pin Description |
| :---: | :---: | :---: | :--- |
| 1 | ON | Input | A low-to-high transition on this pin closes the power switch. ON is an asserted-HIGH, <br> level-sensitive CMOS input with ON_V $V_{I L}<0.3 \mathrm{~V}$ and ON_V $\mathrm{V}_{\mathrm{IH}}$ _NI $>1.2 \mathrm{~V}$. Connect this pin <br> to the output of a general-purpose output (GPO) from a microcontroller or other application <br> processor. A resistor connected in series to ON signal sets the V S Slew Rate. Please read <br> more information on Adjustable Slew Rate description. |
| 2 | D | MOSFET | Drain/Input terminal of Power MOSFET. Connect a $10 \mu \mathrm{~F}$ (or larger) low ESR capacitor <br> from this pin to GND. Capacitors used at D should be rated at 10 V or higher. |
| 3 | S | MOSFET | Source/Output terminal of Power MOSFET. Connect a $10 \mu \mathrm{~F}$ (or larger) low ESR capacitor <br> from this pin to GND. Capacitors used at S should be rated at 10 V or higher. |
| 4 | GND | GND | Ground connection. Connect this pin to system analog or power ground plane. |

## Ordering Information

| Part Number | Type | Production Flow |
| :---: | :---: | :---: |
| SLG59M1440V | STDFN 4L | Industrial, $-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ |
| SLG59M1440VTR | STDFN 4L (Tape and Reel) | Industrial, $-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ |

## Application Diagram



## Adjustable Ramp Rate vs. ON Pin Current (5.5 V, $25^{\circ} \mathrm{C}$ )

| ON Pin Current | $\mathbf{V}_{\mathbf{S ( S R )}}$ (typ) |
| :---: | :---: |
| $20 \mu \mathrm{~A}$ | $0.56 \mathrm{~V} / \mathrm{ms}$ |
| $50 \mu \mathrm{~A}$ | $1.34 \mathrm{~V} / \mathrm{ms}$ |
| $100 \mu \mathrm{~A}$ | $2.53 \mathrm{~V} / \mathrm{ms}$ |
| $150 \mu \mathrm{~A}$ | $3.71 \mathrm{~V} / \mathrm{ms}$ |
| $200 \mu \mathrm{~A}$ | $4.68 \mathrm{~V} / \mathrm{ms}$ |
| $250 \mu \mathrm{~A}$ | $5.63 \mathrm{~V} / \mathrm{ms}$ |

## Adjustable Slew Rate (ON Pin 1)

SLG59M1440V has a built in configurable slew control feature. The configurable slew control uses current detection method on Pin 1. When ON voltage rises above $\mathrm{ON} \mathrm{V}_{\mathrm{IH}} \mathrm{INI}(1.2 \mathrm{~V}$ typical), the slew control circuit will measure the current flowing into Pin 1. Based on the current flowing into pin 1, different slew rates will be selected by the internal control circuit. See ON Pin Curent vs. $\mathrm{V}_{\mathrm{S}(\mathrm{SR})}$ table. The slew rate is configurable by selecting a different R 1 resistor value as shown on application diagram. Calculating the R1 value depends on both the desired slew rate, and the GPIO_ $V_{O H}$ level of the device driving the ON Pin 1.

ON Pin Current $=\left(\right.$ GPIO_ $\mathrm{V}_{\mathrm{OH}}-\mathrm{ON} \mathrm{V}_{\text {REF }}(1.05 \mathrm{~V}$ typical $\left.)\right) / \mathrm{R} 1$

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## Absolute Maximum Ratings

| Parameter | Description | Conditions | Min. | Typ. | Max. | Unit |
| :---: | :--- | :--- | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{D}}$ | Power Switch Input Voltage |  | -- | -- | 6 | V |
| $\mathrm{~T}_{\text {S }}$ | Storage Temperature |  | -65 | -- | 150 | ${ }^{\circ} \mathrm{C}$ |
| ESD $_{\text {HBM }}$ | ESD Protection | Human Body Model | 2000 | -- | -- | V |
| MSL | Moisture Sensitivity Level |  |  | 1 |  |  |
| W $_{\text {DIS }}$ | Package Power Dissipation |  | -- | -- | 0.5 | W |
| MOSFET IDS | Peak Current from Drain to Source | For no more than 1 ms with $1 \%$ <br> duty cycle | -- | -- | 1.5 | A |

Note: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

## Electrical Characteristics

$\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ unless otherwise noted. Typical values are at $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.

| Parameter | Description | Conditions | Min. | Typ. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $V_{D}$ | Power Switch Input Voltage | $-40^{\circ} \mathrm{C}$ to $85{ }^{\circ} \mathrm{C}$ | 2.5 | -- | 5.5 | V |
| $I_{\text {D }}$ | Power Switch Current (PIN 2) | when OFF | -- | 0.1 | 1 | $\mu \mathrm{A}$ |
|  |  | when ON, No load | -- | 18 | 30 | $\mu \mathrm{A}$ |
| $\mathrm{RDS}_{\mathrm{ON}}$ | ON Resistance | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C} ; \mathrm{I}_{\mathrm{DS}}=100 \mathrm{~mA}$ | -- | 40 | 50 | $\mathrm{m} \Omega$ |
|  |  | $\mathrm{T}_{\mathrm{A}}=70^{\circ} \mathrm{C} ; \mathrm{I}_{\mathrm{DS}}=100 \mathrm{~mA}$ | -- | 50 | 55 | $\mathrm{m} \Omega$ |
|  |  | $\mathrm{T}_{\mathrm{A}}=85^{\circ} \mathrm{C} ; \mathrm{I}_{\mathrm{DS}}=100 \mathrm{~mA}$ | -- | 55 | 65 | $\mathrm{m} \Omega$ |
| MOSFET IDS | Current from D to S | Continuous | -- | -- | 1.0 | A |
| TON_Delay | ON Delay Time | $50 \%$ ON to $V_{S}$ Ramp Start; ON Pin Current (PIN1) $=20 \mu \mathrm{~A}$; $\mathrm{V}_{\mathrm{D}}=5 \mathrm{~V} ; \mathrm{C}_{\mathrm{LOAD}}=10 \mu \mathrm{~F} ;$ $R_{\text {LOAD }}=20 \Omega$ | -- | 2.4 | 4.0 | ms |
|  |  | $50 \%$ ON to $90 \% \mathrm{~V}_{\text {S }}$ | Set by External Resistor ${ }^{1}$ |  |  | ms |
| $\mathrm{T}_{\text {Total_ON }}$ | Total Turn On Time | Example: <br> ON Pin Current (PIN1) $=20 \mu \mathrm{~A}$; $\mathrm{V}_{\mathrm{D}}=5 \mathrm{~V} ; \mathrm{C}_{\mathrm{LOAD}}=10 \mu \mathrm{~F} ;$ $R_{\text {LOAD }}=20 \Omega$ | -- | 11.7 | -- | ms |
|  |  | $10 \% \mathrm{~V}_{\mathrm{S}}$ to $90 \% \mathrm{~V}_{\mathrm{S}}$ | Set by External Resistor ${ }^{1}$ |  |  | V/ms |
| $\mathrm{V}_{\mathrm{S}(\mathrm{SR})}$ | $\mathrm{V}_{\text {S }}$ Slew Rate | Example: <br> ON Pin Current (PIN1) $=20 \mu \mathrm{~A}$; $\begin{aligned} & \mathrm{V}_{\mathrm{D}}=5 \mathrm{~V} ; \mathrm{C}_{\mathrm{LOAD}}=10 \mu \mathrm{~F} ; \\ & \mathrm{R}_{\mathrm{LOAD}}=20 \Omega \end{aligned}$ | -- | 0.56 | -- | V/ms |
| $\mathrm{R}_{\text {DISCHRG }}$ | Discharge Resistance | $\mathrm{V}_{\mathrm{D}}=2.5 \mathrm{~V}$ to $5.5 \mathrm{~V} ; \mathrm{V}_{\mathrm{S}}=0.4 \mathrm{~V}$ Input bias | 100 | 150 | 300 | $\Omega$ |
| $\mathrm{C}_{\text {LOAD }}$ | Output Load Capacitance | $\mathrm{C}_{\text {LOAD }}$ connected from S to GND | -- | -- | 100 | $\mu \mathrm{F}$ |
| ON_V VEF | ON Pin Reference Voltage ${ }^{2}$ |  | 0.99 | 1.05 | 1.10 | V |
| ON_V $\mathrm{V}_{\text {IH_INI }}$ | Initial Turn On Voltage | Internal Charge Pump ON | 1.2 | -- | $\mathrm{V}_{\mathrm{D}}$ | V |
| ON_V ${ }_{\text {IL }}$ | Low Input Voltage on ON pin | Internal Charge Pump OFF | -0.3 | 0 | 0.3 | V |
| ON_R | Input Impedance on ON pin |  | 100 | -- | -- | M ת |
| THERM ${ }_{\text {ON }}$ | Thermal shutoff turn-on temperature |  | -- | 120 | -- | ${ }^{\circ} \mathrm{C}$ |
| THERM ${ }_{\text {OFF }}$ | Thermal shutoff turn-off temperature |  | -- | 100 | -- | ${ }^{\circ} \mathrm{C}$ |

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## Electrical Characteristics (continued)

$\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ unless otherwise noted. Typical values are at $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.

| Parameter | Description | Conditions | Min. | Typ. | Max. | Unit |
| :---: | :--- | :--- | :---: | :---: | :---: | :---: |
| THERM $_{\text {TIME }}$ | Thermal shutoff time |  | -- | -- | 1 | ms |
| $T_{\text {OFF_Delay }}$ | OFF Delay Time | $50 \%$ ON to $V_{S}$ Fall Start; $V_{D}=5 \mathrm{~V} ;$ <br> $R_{\text {LOAD }}=20 \Omega$, no $C_{\text {LOAD }}$ | -- | 6.5 | 20 | $\mu \mathrm{~s}$ |
| $\mathrm{~T}_{\text {FALL }}$ | $V_{S}$ Fall Time | $90 \% \mathrm{~V}_{S}$ to $10 \% \mathrm{~V}_{S} ; \mathrm{V}_{\mathrm{D}}=5 \mathrm{~V} ;$ <br> $R_{\text {LOAD }}=20 \Omega ;$ no $C_{\text {LOAD }}$ | -- | 1.2 | 2 | $\mu \mathrm{~s}$ |

## Notes:

1. Refer to table for configuration details.
2. Voltage before ON pin resistor needs to be higher than 1.2 V to generate required $\mathrm{I}_{\mathrm{ON}}$
$\mathrm{T}_{\mathrm{ON} \text { _Delay }}, \mathrm{V}_{\mathrm{S}(\mathrm{SR})}$, and $\mathrm{T}_{\text {Total_ON }}$ Timing Details


An Ultra-small $40 \mathrm{~m} \Omega, 1 \mathrm{~A}$,
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Typical Performance Characteristics
Slew Rate vs. ON Pin Current


T Total_on ${ }^{\text {vs. ON Pin Current }}$


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## SLG59M1440V Power-Up/Power-Down Sequence Considerations

A nominal power-up sequence is to apply $\mathrm{V}_{\mathrm{D}}$ and toggle the ON pin LOW-to-HIGH after $\mathrm{V}_{\mathrm{D}}$ is at least $90 \%$ of its final value. A nominal power-down sequence is the power-up sequence in reverse order. If $\mathrm{V}_{\mathrm{D}}$ ramp is too fast, a voltage glitch may appear on the output pin at $S$. To prevent glitches at the output, it is recommended to connect at least $0.1 u F$ capacitor from the $S$ pin to GND and to keep the $\mathrm{V}_{\mathrm{D}}$ ramp time higher than 2 ms .

## Power Dissipation Considerations

The junction temperature of the SLG59M1440V depends on factors such as board layout, ambient temperature, external air flow over the package, load current, and the $\mathrm{RDS}_{\mathrm{ON}}$-generated voltage drop across the power MOSFET. While the primary contributor to the increase in the junction temperature of the SLG59M1440V is the power dissipation of its power MOSFETs, its power dissipation and the junction temperature in nominal operating mode can be calculated using the following equations:

$$
\mathrm{PD}_{\text {TOTAL }}=\mathrm{RDS}_{\mathrm{ON}} \times \mathrm{I}_{\mathrm{DS}}{ }^{2}
$$

where:
$\mathrm{PD}_{\text {TOTAL }}=$ Total package power dissipation, in Watts $(\mathrm{W})$
RDS $_{\text {ON }}=$ Power MOSFET ON resistance, in Ohms ( $\Omega$ )
$\mathrm{I}_{\mathrm{DS}}=$ Output current, in Amps (A)
and

$$
\mathrm{T}_{J}=\mathrm{PD}_{\text {TOTAL }} \times \theta_{J A}+\mathrm{T}_{\mathrm{A}}
$$

where:
$\mathrm{T}_{\mathrm{J}}=$ Die junction temperature, in Celsius degrees $\left({ }^{\circ} \mathrm{C}\right)$
$\theta_{\mathrm{JA}}=$ Package thermal resistance, in Celsius degrees per Watt ( ${ }^{\circ} \mathrm{C} / \mathrm{W}$ ) - highly dependent on pcb layout
$\mathrm{T}_{\mathrm{A}}=$ Ambient temperature, in Celsius degrees ( ${ }^{\circ} \mathrm{C}$ )
In nominal operating mode, the SLG59M1440V's power dissipation can also be calculated by taking into account the voltage drop across the switch $\left(V_{D}-V_{S}\right)$ and the magnitude of the switch's output current ( $l_{D S}$ ):

$$
\begin{gathered}
\mathrm{PD}_{\text {TOTAL }}=\left(\mathrm{V}_{\mathrm{D}}-\mathrm{V}_{\mathrm{S}}\right) \times \mathrm{I}_{\mathrm{DS}} \text { or } \\
\mathrm{PD}_{\text {TOTAL }}=\left(\mathrm{V}_{\mathrm{D}}-\left(\mathrm{R}_{\mathrm{LOAD}} \times \mathrm{I}_{\mathrm{DS}}\right)\right) \times \mathrm{I}_{\mathrm{DS}}
\end{gathered}
$$

where:
$\mathrm{PD}_{\text {TOTAL }}=$ Total package power dissipation, in Watts (W)
$V_{D}=$ Switch input Voltage, in Volts (V)
$\mathrm{R}_{\text {LOAD }}=$ Output Load Resistance, in Ohms ( $\Omega$ )
$\mathrm{I}_{\mathrm{DS}}=$ Switch output current, in Amps (A)
$V_{S}=$ Switch output voltage, or $R_{\text {LOAD }} \times I_{D S}$

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## Layout Guidelines:

1. Since the $D$ and $S$ pins dissipate most of the heat generated during high-load current operation, it is highly recommended to make power traces as short, direct, and wide as possible. A good practice is to make power traces with an absolute minimum width of 15 mils $(0.381 \mathrm{~mm})$ per Ampere. A representative layout, shown in Figure 1, illustrates proper techniques for heat to transfer as efficiently as possible out of the device;
2.To minimize the effects of parasitic trace inductance on normal operation, it is recommended to connect input $\mathrm{C}_{\mathrm{IN}}$ and output C $_{\text {LOAD }}$ low-ESR capacitors as close as possible to the SLG59M1440V's D and S pins;
2. The GND pin should be connected to system analog or power ground plane.
3. 2 oz . copper is recommended for high current operation.

## SLG59M1440V Evaluation Board:

A GFET3 Evaluation Board for SLG59M1440V is designed according to the statements above and is illustrated on Figure 1. Please note that evaluation board has D_Sense and S_Sense pads. They cannot carry high currents and dedicated only for $\mathrm{RDS}_{\mathrm{ON}}$ evaluation.

Please solder your SLG59M1440V here


Figure 1. SLG59M1440V Evaluation Board.

An Ultra-small $40 \mathrm{~m} \Omega, 1 \mathrm{~A}$,
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Figure 2. SLG59M1440V Evaluation Board Connection Circuit.

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## Basic Test Setup and Connections



Figure 3. Typical connections for GFET3 Evaluation.

## EVB Configuration

1. Connect oscilloscope probes to D/VIN, S/VOUT, ON, etc.;
2. Turn on Power Supply 1 and set desired $\mathrm{V}_{\mathrm{D}}$ from 2.5 V ... 5.5 V range;
3. Toggle the ON signal High or Low to observe SLG59M1440V operation.

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## SLG59M1440V Layout Suggestion



Note: All dimensions shown in micrometers ( $\mu \mathrm{m}$ )

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## Package Top Marking System Definition



NN - Part Serial Number Field Line 1
where each "N" character can be A-Z and 0-9

+     - Part Serial Number Field Line 2
where "+" character can be +, -, =, or blank

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## Package Drawing and Dimensions

4 Lead STDFN Package $1.0 \times 1.0 \mathrm{~mm}$
Index Area (D/2 x E/2)


Unit: mm

| Symbol | Min | Nom. | Max | Symbol | Min | Nom. | Max |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| A | 0.50 | 0.55 | 0.60 | D | 0.95 | 1.00 | 1.05 |
| A1 | 0.005 | - | 0.060 | E | 0.95 | 1.00 | 1.05 |
| A2 | 0.10 | 0.15 | 0.20 | L | 0.35 | 0.40 | 0.45 |
| b | 0.15 | 0.20 | 0.25 | S | 0.2 REF |  |  |
| e | 0.40 BSC |  |  |  |  |  |  |

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Tape and Reel Specifications

| Package Type | \# of Pins | Nominal Package Size [mm] | Max Units |  |  <br> Hub Size [mm] | Leader (min) |  | Trailer (min) |  | Tape Width [mm] | Part Pitch [mm] |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | per Reel | per Box |  | Pockets | Length [mm] | Pockets | Length [mm] |  |  |
| STDFN 4L Green | 4 | $1.0 \times 1.0 \times 0.55$ | 8000 | 8000 | 178 / 60 | 200 | 400 | 200 | 400 | 8 | 2 |

## Carrier Tape Drawing and Dimensions

| Package Type | PocketBTM <br> Length | $\begin{aligned} & \text { Pocket BTM } \\ & \text { Width } \end{aligned}$ | Pocket Depth | Index Hole Pitch | Pocket Pitch | Index Hole Diameter | Index Hole to Tape Edge | Index Hole to Pocket Center | Tape Width |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | A0 | B0 | K0 | P0 | P1 | D0 | E | F | W |
| STDFN 4L Green | 1.16 | 1.16 | 0.63 | 4 | 2 | 1.5 | 1.75 | 3.5 | 8 |



Refer to EIA-481 specification

## Recommended Reflow Soldering Profile

Please see IPC/JEDEC J-STD-020: latest revision for reflow profile based on package volume of $0.55 \mathrm{~mm}^{3}$ (nominal). More information can be found at www.jedec.org.

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Revision History

| Date | Version | Change |
| :---: | :---: | :--- |
| $9 / 1 / 2020$ | 1.13 | Updated Style and Formatting <br> Updated Charts <br> Added Layout Guidelines |
| $11 / 20 / 2017$ | 1.12 | Updated Package Marking Definition <br> Updated Layout Suggestion |
| $12 / 11 / 2013$ | 1.11 | changed temp range to -40 to 85C |

